Low Temperature Co-fired Multilayer Ceramic Substrates

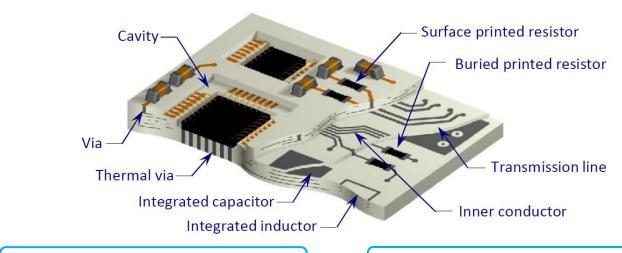


Multilayer ceramics and cavity packages enable complex module creation

- Highly controlled dimensions, flatness
- Low thermal expansion enhances bare IC's use
- Ceramics with low dielectric constant & loss
- Low ohm silver conductor

Optimal for bare chip module

High frequency performance

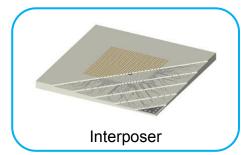


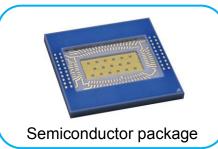
Miniaturization & Integration

Environmental & reliability

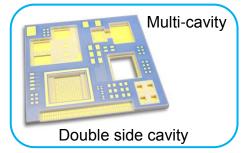
- Multilayer, multi & double side cavity
- Surface & buried printed resistors
- High heat/moisture resistance (zero water absorption)
- Outgas/dust free, impermeability

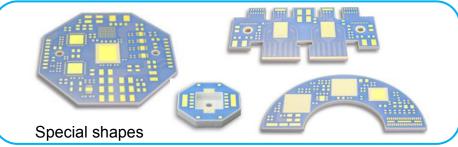
Application Examples











For more information, please contact:

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Phone: +49 (0)4821 89890, E-Mail: koa-europe@koaeurope.de, Internet: www.koaeurope.de

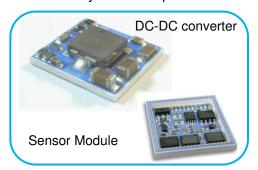
Low Temperature Co-fired Multilayer Ceramic Substrates

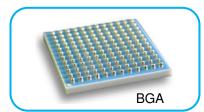


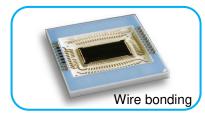
■ Pilot to Mass Production, Module Assembly

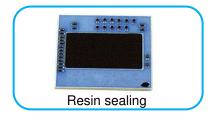
Module Assembly

- Total support from design to assembly
- · Reliability test on request









High Flexibility

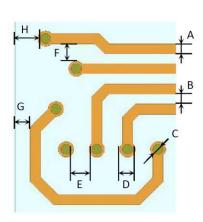
- Small to large volume production
- Low initial costs

Material Characteristics

| Parameter | Characteristics | |
|---------------------------------|-------------------|---------------------|
| Bending strength | 250 | MPa |
| Thermal expansion coefficient | 5.5 | ppm / K |
| Thermal conductivity | 3 | W / m • K |
| Insulation resistance | >10 ¹³ | Ω • cm |
| Dielectric constant | 6.8 (7) | at 75 GHz (1MHz) |
| Dielectric loss | < 0.01 (0.003) | at 75 GHz (1MHz) |
| Resistivity of buried conductor | Ag: 2.5 | μΩ • cm |
| Density | 2.8 | g / cm ³ |
| Surface roughness Ra | < 0.4 | μm |
| Withstanding voltage | > 15 | kV / mm |
| Layer thickness | 80 / 100 /125 | μm |

Design Rules

| Symbol | Parameter | Standard | Special |
|--------|--------------------------------|-----------------|--------------|
| Α | Line width | 0.06 mm Min | 0.05 mm Min |
| В | Line to line spacing | 0.06 mm Min | 0.05 mm Min |
| С | Via diameter | 0.1 mm, 0.15 mm | 0.06 mm Min |
| D | Via pad diameter | C + 0.05 mm Min | Pad less |
| E | Via to Via spacing | 0.2 mm Min | 0.08 mm Min |
| F | Via to line spacing | 0.125 mm Min | 0.075 mm Min |
| G | Part edge to conductor spacing | 0.2 mm Min | 0.10 mm Min |
| Н | Part edge to Via pad spacing | 0.3 mm Min | 0.15 mm Min |
| J1, J2 | Cavity width | 0.6 mm Min | 0.20 mm Min |
| K1, K2 | Cavity depth | 0.1 mm Min | 0.08 mm Min |
| L | Cavity wall thickness | 0.5 mm Min | - |
| M | Shelf width in the cavity | 0.5 mm Min | 0.01 mm Min |



* Please contact us for

special design rules

TK1 K2

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J1

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